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LCD PIXEL CIRCUIT****Publication Classification**(51) **Int. Cl.****G02F 1/1362** (2006.01)**G02F 1/1368** (2006.01)**G02F 1/1335** (2006.01)(52) **U.S. Cl.**CPC **G02F 1/136286** (2013.01); **G02F 1/1368**
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G02F 2201/123 (2013.01); **G02F 2001/136295**
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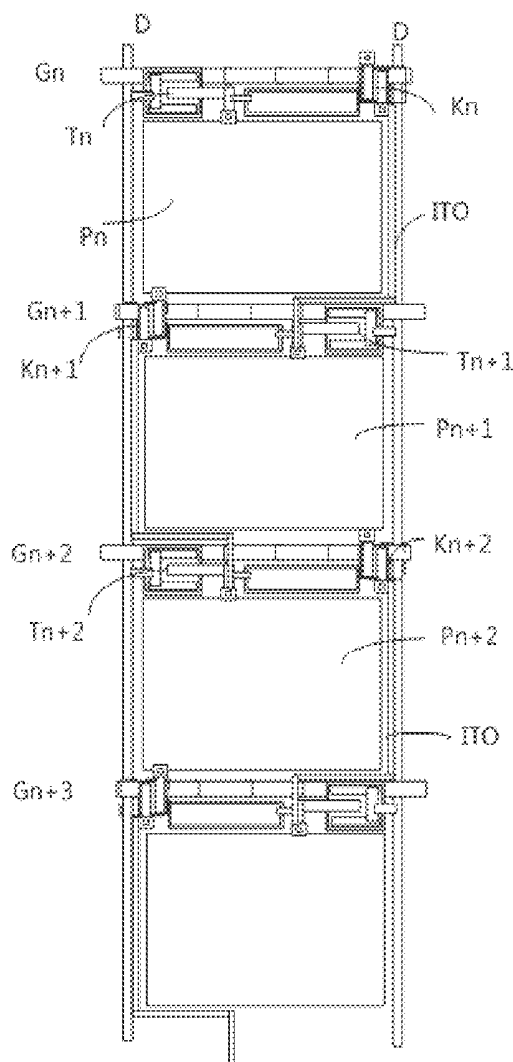
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ABSTRACT

An LCD array substrate, an LCD panel and an LCD pixel circuit are disclosed. The LCD array substrate includes: a substrate and a plurality of gate lines and data lines, wherein the gate lines and the data lines are crossed with each other to form a plurality of pixel units; each of the pixel units is provided with a pixel electrode, a first thin-film transistor, and a connecting switch controlled by the corresponding gate line; the switch is controlled to be turned on.



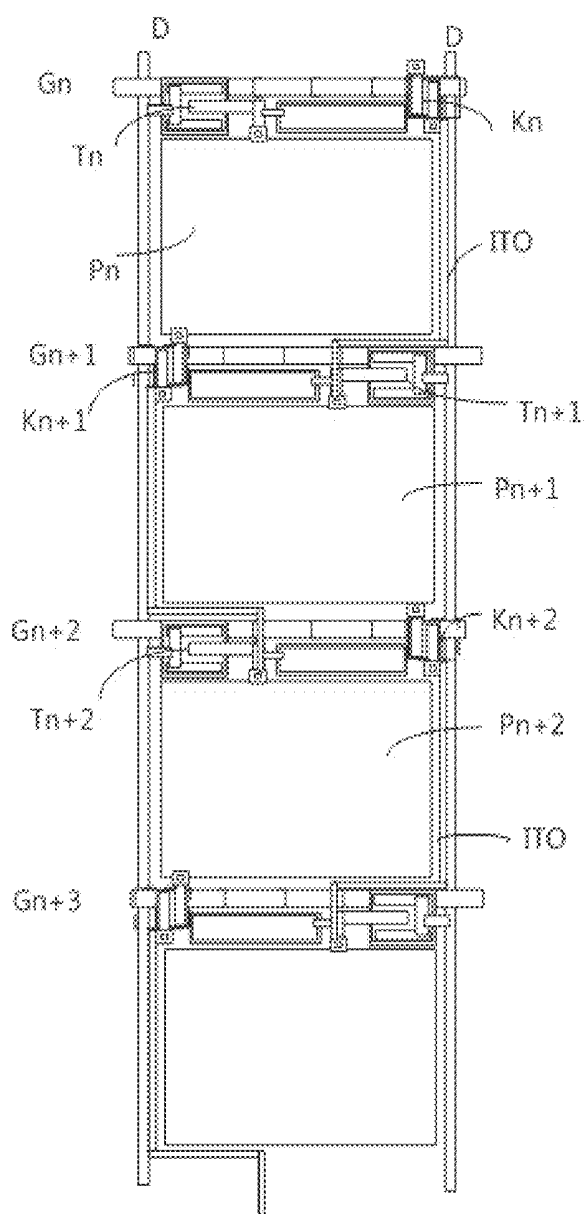


FIG. 1

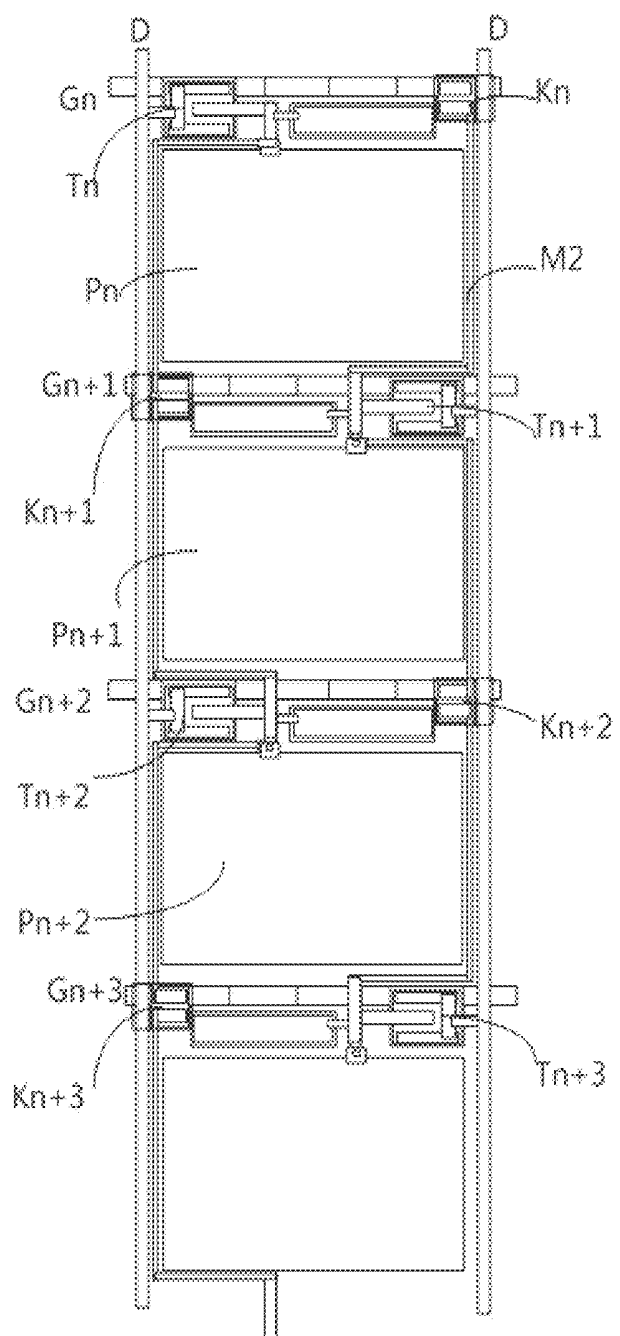


FIG. 2

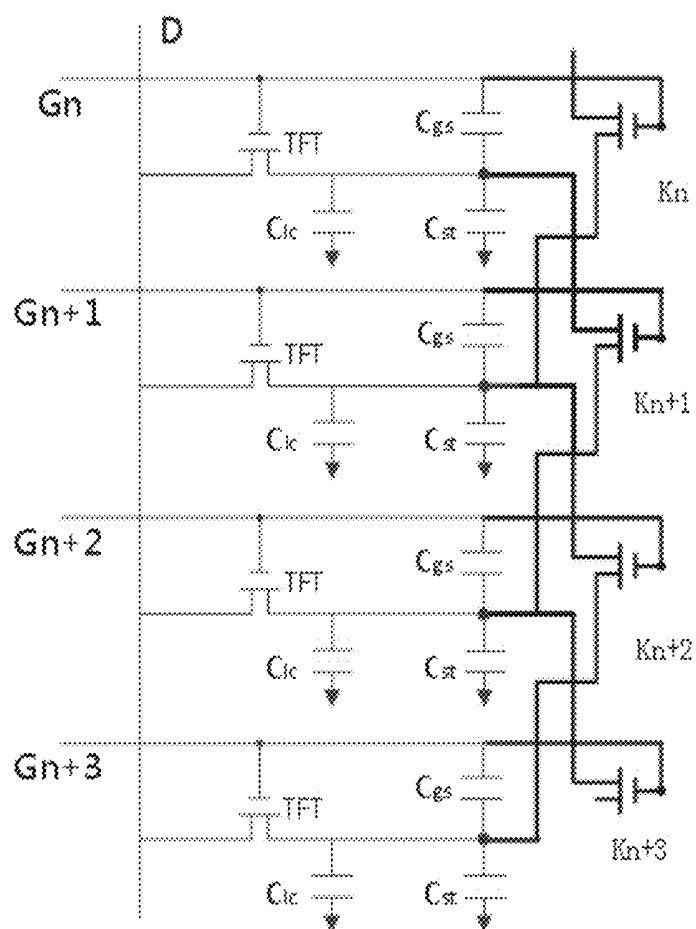


FIG. 3

LCD ARRAY SUBSTRATE, LCD PANEL AND LCD PIXEL CIRCUIT

BACKGROUND OF THE INVENTION

Field of the Invention

[0001] The present invention relates to the technical field of liquid crystal display technology, and more particularly to an LCD array substrate, an LCD panel and an LCD pixel circuit.

Description of the Related Art

[0002] An LCD (Liquid Crystal Display) uses the change of electric field strength on liquid crystal molecules to change the orientation of the liquid crystal molecules so as to control the strength of light to display images. Currently, a liquid crystal display apparatus has been widely used in terminal display devices having any sizes due to its features of light-weight, small-volume and thin-thickness. An LCD is mainly formed by an array substrate and a color-filter substrate. The array substrate is provided with gate lines, data lines, pixel electrodes and thin-film transistors. Each of the pixel electrodes is controlled by the corresponding thin-film transistor. When the thin-film transistor is turned on, the pixel electrode is being charged during the turned-on time. After the thin-film transistor is turned off, the pixel electrode maintains its voltage until next scanning for recharging.

[0003] Due to a voltage coupling effect of the thin-film transistors, at the moment when an electric potential of a gate signal decreases from a high level, a pixel charging voltage will have a change of a voltage difference ΔV . ΔV means a feed-through voltage. In general, a feed-through phenomenon is a problem that a liquid crystal panel may often encounter. The existence of feed-through phenomenon will cause a brightness difference between a frame of positive polarity frame and a frame of negative polarity, and then cause the panel to have a flicker problem and increase the risk of image sticking. Therefore, the feed-through voltage needs to be reduced by all means when designing the panel. The influence of a feed-through phenomenon performed on the pixel electric potential may be referred to $\Delta V = (V_{off} - V_{on}) \cdot C_{gs} / C_{total}$, wherein V_{off} and V_{on} are a turn-off voltage and a turn-on voltage of a scanning line as shown in FIG. 1; C_{total} is the capacitor of the pixel electrode which generally includes three capacitors: $C_{total} = C_{gs}$ (parasitic capacitor of a TFT) + C_{st} (storage capacitor) + C_{lc} (liquid crystal capacitor). It can be seen from the foregoing formula that the value of ΔV can be lower by reducing C_{gs} or increasing C_{total} . Generally, the feed-through voltage is reduced by a way of increasing C_{st} . The larger C_{st} is, the less the amount of voltage coupling is. However, C_{st} is usually limited by conditions such as an aperture ratio and thus cannot be made larger.

[0004] Therefore, the conventional technologies still have defects, and require more improvements.

SUMMARY OF THE INVENTION

[0005] An objective of the present invention is to provide an LCD array substrate and an LCD pixel circuit so as to solve the problem that the feed-through voltage may influence display quality in the conventional technology.

[0006] In order to solve the foregoing problem, the present invention provides a technical solution as follows:

[0007] The present invention provides an LCD array substrate including: a substrate and a plurality of gate lines and data lines, wherein the gate lines and the data lines are crossed with each other to form a plurality of pixel units; each of the pixel units is provided with a pixel electrode, a first thin-film transistor, and a connecting switch controlled by the corresponding gate line; the connecting switch is disposed between a pixel electrode of one pixel unit which is at the same column and at a preceding row in relation to the pixel unit where the connecting switch belongs and a pixel electrode of another pixel unit which is at the same column and at a following row in relation to the pixel unit where the connecting switch belongs; the connecting switch is controlled to be turned on so that the pixel electrode of one pixel unit which is at the same column and at a preceding row in relation to the pixel unit where the connecting switch belongs and the pixel electrode of another pixel unit which is at the same column and at a following row in relation to the pixel unit where the connecting switch belongs are electrically connected.

[0008] In the LCD array substrate of the present invention, the connecting switch is a second thin-film transistor; a gate of the second thin-film transistor is connected to a gate line in the pixel unit where the second thin-film transistor belongs, a source thereof is connected to a pixel electrode of an adjacent pixel unit which is at the same column and at a preceding row, and a drain thereof is connected to a pixel electrode of another adjacent pixel unit which is at the same column and at a following row.

[0009] In the LCD array substrate of the present invention, each of the pixel units is further provided with metallic lines; the source of the second thin-film transistor is connected to the pixel electrode of the adjacent pixel unit which is at the same column and at a preceding row through one of the metallic lines; the drain of the second thin-film transistor is connected to the pixel electrode of another adjacent pixel unit which is at the same column and at a following row through another one of the metallic lines.

[0010] In the LCD array substrate of the present invention, the metallic lines are ITO lines; the ITO lines are mounted in the same layer with the pixel electrodes.

[0011] In the LCD array substrate of the present invention, each of the pixel units further includes an M2 metal layer; the metallic lines are M2 metallic lines; the metallic lines are mounted in the same layer with the M2 metal layer.

[0012] The present invention further provides an LCD panel, the LCD panel includes a color-filter substrate, a liquid crystal layer, and an LCD array substrate; the color-filter substrate is mounted opposite to the LCD array substrate; the liquid crystal layer is mounted between the color-filter substrate and the LCD array substrate; the LCD array substrate includes a substrate and a plurality of gate lines and data lines, wherein the gate lines and the data lines are crossed with each other to form a plurality of pixel units; each of the pixel units is provided with a pixel electrode, a first thin-film transistor, and a connecting switch controlled by the corresponding gate line; the connecting switch is controlled to be turned on so that the pixel electrode of one pixel unit which is at the same column and at a preceding row in relation to the pixel unit where the connecting switch belongs and the pixel electrode of another pixel unit which

is at the same column and at a following row in relation to the pixel unit where the connecting switch belongs are electrically connected.

[0013] The present invention further provides an LCD pixel circuit including: a plurality of gate lines, a plurality of data lines, a plurality of pixel units defined by the gate lines and the data lines being crossed with each other; each of the pixel units includes: a first thin-film transistor, a capacitor; the capacitor is connected to one of the data lines through the first thin-film transistor; each of the pixel units further includes: a connecting switch being controlled by the corresponding gate line; the connecting switch controls the connection or disconnection of the drain of the first thin-film transistor of an adjacent pixel unit which is at the same column and at a preceding row in relation to the pixel unit where the connecting switch belongs and the drain of the first thin-film transistor of another adjacent pixel unit which is at the same column and at a following row in relation to the pixel unit where the connecting switch belongs.

[0014] In the LCD pixel circuit of the present invention, the connecting switch is a second thin-film transistor; a gate of the second thin-film transistor is connected to a gate line in the pixel unit where the second thin-film transistor belongs, a source thereof is connected to a drain of a first thin-film transistor of an adjacent pixel unit which is at the same column and at a preceding row, and a drain of the second thin-film transistor is connected to a drain of a first thin-film transistor of another adjacent pixel unit which is at the same column and at a following row.

[0015] In the LCD pixel circuit of the present invention, when an input to the gate line is at a high electric potential, the second thin-film transistor is turned on, the drain of the first thin-film transistor of the adjacent pixel unit which is at the same column and at a preceding row and the drain of the first thin-film transistor of the another adjacent pixel unit which is at the same column and at a following row are connected to each other.

[0016] In the LCD pixel circuit of the present invention, the capacitor includes a parasitic capacitor, a liquid crystal capacitor and a storage capacitor.

[0017] Compared with the conventional technology, each of the pixel units in the present invention is further added with a connecting switch that connects a pixel electrode of an adjacent pixel unit at the preceding row and a pixel electrode of another adjacent pixel unit at the following row so as to increase the overall capacitance, thereby further avoiding the occurrence of feed-through voltage and reducing the risk of image sticking.

BRIEF DESCRIPTION OF THE DRAWINGS

[0018] FIG. 1 is a plane view of an LCD array substrate according to a preferred embodiment of the present invention;

[0019] FIG. 2 is a plane view of an LCD array substrate according to another preferred embodiment of the present invention; and

[0020] FIG. 3 is a partial circuit diagram of an LCD pixel circuit according to a preferred embodiment of the present invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0021] The foregoing objects, features and advantages adopted by the present invention can be best understood by

referring to the following detailed description of the preferred embodiments and the accompanying drawings. Furthermore, the directional terms described in the present invention, such as upper, lower, front, rear, left, right, inner, outer, side and etc., are only directions referring to the accompanying drawings, so that the used directional terms are used to describe and understand the present invention, but the present invention is not limited thereto.

[0022] In the drawings, similar structural units are designated by the same reference numerals.

[0023] Please refer to FIG. 1, which is a plane view of an LCD array substrate according to a preferred embodiment of the present invention. The LCD array substrate includes: a substrate (not shown in the drawing), a plurality of gate lines (marked as $G_n, G_{n+1}, G_{n+2}, G_{n+3}, \dots$), and a plurality of data lines (marked as $D_n, D_{n+1}, D_{n+2}, D_{n+3}, \dots$). The gate lines and the data lines are crossed with each other to form a plurality of pixel units (presented as $n, n+1, \dots$). Each of the pixel units (n) is provided with a pixel electrode P_n , a first thin-film transistor T_n , and a connecting switch K_n controlled by the corresponding gate line. The connecting switch K_n is disposed between a pixel electrode P_{n-1} of one pixel unit ($n-1$) which is at the same column and at a preceding row in relation to the pixel unit (n) where the connecting switch K_n belongs and a pixel electrode P_{n+1} of another pixel unit ($n+1$) which is at the same column and at a following row in relation to the pixel unit (n) where the connecting switch K_n belongs. The connecting switch K_n may connect the pixel electrode P_{n-1} of the pixel unit ($n-1$) which is at the same column and at a preceding row in relation to the pixel unit (n) where the connecting switch K_n belongs and the pixel electrode P_{n+1} of another pixel unit ($n+1$) which is at the same column and at a following row in relation to the pixel unit (n) where the connecting switch K_n belongs. The turn-on or turn-off status of the connecting switch K_n is controlled by inputting different electric potentials to the gate line G_n , thereby controlling the connection or disconnection between the pixel electrode P_{n-1} of the pixel unit ($n-1$) which is at the same column and at a preceding row in relation to the pixel unit (n) where the connecting switch K_n belongs and the pixel electrode P_{n+1} of another pixel unit ($n+1$) which is at the same column and at a following row in relation to the pixel unit (n) where the connecting switch K_n belongs. A gate of the first thin-film transistor T_n is connected to the corresponding gate line G_n ; a source thereof is connected to a corresponding data line; a drain thereof is connected to a pixel electrode P_n .

[0024] Furthermore, the connecting switch K_n is preferably a second thin-film transistor K_n . The specific structure of the second thin-film transistor K_n may be identical to the structure of the first thin-film transistor, but it is not limited thereto.

[0025] Specifically, a gate of the second thin-film transistor K_n is connected to the corresponding gate line G_n ; a source thereof is connected to a pixel electrode P_{n-1} of an adjacent pixel unit ($n-1$) which is at the same column and at a preceding row, and a drain thereof is connected to a pixel electrode P_{n+1} of another adjacent pixel unit ($n+1$) which is at the same column and at a following row.

[0026] In a preferred technical solution of this embodiment, the pixel unit is further provided with metallic lines L ; the source of the second thin-film transistor is connected to the pixel electrode P_{n-1} of the adjacent pixel unit ($n-1$) which is at the same column and at a preceding row through

one of the metallic lines L; the drain of the second thin-film transistor is connected to the pixel electrode P_{n+1} of another adjacent pixel unit (n+1) which is at the same column and at a following row through another one of the metallic lines L.

[0027] In a preferred technical solution of this embodiment, the metallic lines L are ITO lines. The ITO lines are mounted in the same layer with the pixel electrodes (as shown in FIG. 1); with the ITO lines, the connections of the pixel electrode at the preceding row and the pixel electrode at the following row are achieved.

[0028] In another preferred technical solution of the present embodiment, as shown in FIG. 2, which is a plane view of an LCD array substrate according to another preferred embodiment of the present invention, the array substrate further includes an M1 metal layer (not shown in the drawing) and an M2 metal layer. The metallic lines are the M2 metallic lines. The metallic lines are mounted in the same layer with the M2 metal layer. With the M2 metallic lines, the connections of the pixel electrode at the preceding row and the pixel electrode at the following row are achieved.

[0029] In a preferred technical solution of this embodiment, as shown in FIGS. 1 and 2, the first thin-film transistor T_n and the second thin-film transistor K_n are mounted at two ends of the pixel unit n.

[0030] In this embodiment, the specific work principle of the array substrate is:

[0031] when charging the pixels at G_n row, in a chronological order: G_n is inputted with a high electric potential at a preceding period to perform a pre-charging; then G_{n+1} is inputted with a high electric potential; then the data line D_n is inputted with an image signal and starts to charge the pixel electrode P_n ; since G_{n+1} is currently at a high electric potential, the second thin-film transistor K_{n+1} of the same pixel unit (n) is now turned on so that the pixel electrode P_n and the pixel electrode P_{n+2} are connected. At this time, the data line D_n is charging four capacitors: C_{lc} (liquid crystal capacitor) at the n-th row, C_{st} (storage capacitor), C_{lc} (liquid crystal capacitor) at the (n+2)th row, and C_{st} (storage capacitor). Under a regular driving, the polarity at the n-th row and at the (n+2)th row are the same, therefore the charging is fast. G_n is then closed, and the charging is finished; since at this time the second thin-film transistor K_{n+1} is still turned on, the influence of a feed-through voltage will be equally shared by superposition of the four capacitors. When G_{n+1} is closed, the second thin-film transistor K_{n+1} is turned off, and the pixel electrode P_n and the pixel electrode P_{n+2} are disconnected, therefore the charging of the pixel electrode P_{n+2} will not be affected. Since the feed-through voltage ΔV equals to $(V_{off} - V_{on}) \cdot C_{gs} / 2 \cdot (C_{gs} + C_{st} + C_{lc})$, ΔV is much less than normal design.

[0032] In this embodiment, each of the pixel units is further added with a connecting switch that connects a pixel electrode of an adjacent pixel unit at the preceding row and a pixel electrode of another adjacent pixel unit at the following row so as to increase the overall capacitance, thereby further avoiding the occurrence of feed-through voltage and reducing the risk of image sticking.

[0033] The present invention further provides an LCD panel. The LCD panel includes a color-filter substrate, a liquid crystal layer, and an LCD array substrate; the color-filter substrate is mounted opposite to the LCD array substrate; the liquid crystal layer is mounted between the color-filter substrate and the LCD array substrate. The

specific structure and work principle of the LCD array substrate are substantially the same as the description in the foregoing embodiment, and will not be described herein again to avoid redundancy.

[0034] In this embodiment, each of the pixel units is further added with a connecting switch that connects a pixel electrode of an adjacent pixel unit at the preceding row and a pixel electrode of another adjacent pixel unit at the following row so as to increase the overall capacitance, thereby further avoiding the occurrence of feed-through voltage and reducing the risk of image sticking.

[0035] The present invention further provides an LCD pixel circuit, as shown in FIG. 3, which is a partial circuit diagram of an LCD pixel circuit according to a preferred embodiment of the present invention. The LCD pixel circuit includes: a plurality of gate lines G (marked as $G_n, G_{n+1}, G_{n+2}, G_{n+3}, \dots$), a plurality of data lines D (marked as $D_n, D_{n+1}, D_{n+2}, D_{n+3}, \dots$), and a plurality of pixel units (n) defined by the gate lines and the data lines being crossed with each other; each of the pixel units includes: a first thin-film transistor TFT, a capacitor C; the capacitor C is connected to one of the data lines D through the first thin-film transistor TFT; each of the pixel units further includes: a connecting switch K being controlled by the corresponding gate line G. The connecting switch K may connect the pixel electrode P_{n-1} of the pixel unit (n-1) which is at the same column and at a preceding row in relation to the pixel unit (n) where the connecting switch K belongs and the pixel electrode P_{n+1} of another pixel unit (n+1) which is at the same column and at a following row in relation to the pixel unit (n) where the connecting switch K belongs. The turn-on or turn-off status of the connecting switch K is controlled by inputting different electric potentials to the gate line G, thereby controlling the connection or disconnection between the pixel electrode P_{n-1} of the pixel unit (n-1) which is at the same column and at a preceding row in relation to the pixel unit (n) where the connecting switch K belongs and the pixel electrode P_{n+1} of another pixel unit (n+1) which is at the same column and at a following row in relation to the pixel unit (n) where the connecting switch K belongs. A gate of the first thin-film transistor T_n is connected to the corresponding gate line G_n ; a source thereof is connected to a corresponding data line; a drain thereof is connected to a pixel electrode P_n .

[0036] Furthermore, the connecting switch K_n is preferably a second thin-film transistor K_n . The specific structure of the second thin-film transistor K_n may be identical to the structure of the first thin-film transistor, but it is not limited thereto.

[0037] Specifically, a gate of the second thin-film transistor K_n is connected to the corresponding gate line G_n ; a source thereof is connected to a pixel electrode P_{n-1} of an adjacent pixel unit (n-1) which is at the same column and at a preceding row, and a drain thereof is connected to a pixel electrode P_{n+1} of another adjacent pixel unit (n+1) which is at the same column and at a following row.

[0038] Specifically, the capacitor C includes a parasitic capacitor C_{gs} , a liquid crystal capacitor C_{lc} and a storage capacitor C_{st} . An end of the parasitic capacitor C_{gs} is connected to the corresponding gate line; another end of thereof is connected to the pixel electrode and the drain of the first thin-film transistor TFT. The parasitic capacitor C_{gs} ,

the liquid crystal capacitor C_{lc} and the storage capacitor C_{st} are all connected to the data line through the first thin-film transistor TFT.

[0039] The work principle of the pixel circuit of the embodiment is as follows:

[0040] when charging the pixels at G_n row, in a chronological order: G_n is inputted with a high electric potential at a preceding period to perform a pre-charging; then G_{n+1} is inputted with a high electric potential; then the data line D_n is inputted with an image signal and starts to charge the pixel electrode P_n ; since G_{n+1} is currently at a high electric potential, the second thin-film transistor K_{n+1} of the same pixel unit (n) is now turned on so that the pixel electrode P_n and the pixel electrode P_{n+2} are connected. At this time, the data line D_n is charging four capacitors: C_{lc} (liquid crystal capacitor) at the n-th row, C_{st} (storage capacitor), C_{lc} (liquid crystal capacitor) at the (n+2)th row, and C_{st} (storage capacitor). Under a regular driving, the polarity at the n-th row and at the (n+2)th row are the same, therefore the charging is fast. G_n is then closed, and the charging is finished; since at this time the second thin-film transistor K_{n+1} is still turned on, the influence of a feed-through voltage will be equally shared by superposition of the four capacitors. When G_{n+1} is closed, the second thin-film transistor K_{n+1} is turned off, and the pixel electrode P_n and the pixel electrode P_{n+2} are disconnected, therefore the charging of the pixel electrode P_{n+2} will not be affected. Since the feed-through voltage ΔV equals to $(V_{off}-V_{on}) \cdot C_{gs} / 2 \cdot (C_{gs}+C_{st}+C_{lc})$, ΔV is much less than normal design.

[0041] In the present invention, each of the pixel units is further added with a connecting switch that connects a pixel electrode of an adjacent pixel unit at the preceding row and a pixel electrode of another adjacent pixel unit at the following row so as to increase the overall capacitance, thereby further avoiding the occurrence of feed-through voltage and reducing the risk of image sticking.

[0042] In conclusion, although the present invention has been described with reference to the preferred embodiment thereof, it is apparent to those skilled in the art that a variety of modifications and changes may be made without departing from the scope of the present invention which is intended to be defined by the appended claims.

1. An LCD array substrate, comprising: a substrate and a plurality of gate lines and data lines, wherein the gate lines and the data lines are crossed with each other to form a plurality of pixel units; each of the pixel units is provided with a pixel electrode, a first thin-film transistor, and a connecting switch controlled by the corresponding gate line; the connecting switch is disposed between a pixel electrode of one pixel unit which is at the same column and at a preceding row in relation to the pixel unit where the connecting switch belongs and a pixel electrode of another pixel unit which is at the same column and at a following row in relation to the pixel unit where the connecting switch belongs; the connecting switch is controlled to be turned on so that the pixel electrode of the one pixel unit which is at the same column and at the preceding row in relation to the pixel unit where the connecting switch belongs and the pixel electrode of the another pixel unit which is at the same column and at the following row in relation to the pixel unit where the connecting switch belongs are electrically connected.

2. The LCD array substrate as claimed in claim 1, wherein the connecting switch is a second thin-film transistor; a gate

of the second thin-film transistor is connected to a gate line in the pixel unit where the second thin-film transistor belongs, a source thereof is connected to a pixel electrode of an adjacent pixel unit which is at the same column and at a preceding row, and a drain thereof is connected to a pixel electrode of another adjacent pixel unit which is at the same column and at a following row.

3. The LCD array substrate as claimed in claim 2, wherein each of the pixel units is further provided with metallic lines; the source of the second thin-film transistor is connected to the pixel electrode of the adjacent pixel unit which is at the same column and at a preceding row through one of the metallic lines; the drain of the second thin-film transistor is connected to the pixel electrode of another adjacent pixel unit which is at the same column and at a following row through another one of the metallic lines.

4. The LCD array substrate as claimed in claim 3, wherein the metallic lines are ITO lines; the ITO lines are mounted in the same layer with the pixel electrodes.

5. The LCD array substrate as claimed in claim 3, wherein each of the pixel units further includes an M2 metal layer; the metallic lines are M2 metallic lines; the metallic lines are mounted in the same layer with the M2 metal layer.

6. An LCD panel, comprising a color-filter substrate, a liquid crystal layer and further comprising an LCD array substrate as claimed in claim 1, wherein the color-filter substrate is mounted opposite to the LCD array substrate; the liquid crystal layer is mounted between the color-filter substrate and the LCD array substrate.

7. An LCD pixel circuit, comprising: a plurality of gate lines, a plurality data lines, a plurality of pixel units defined by the gate lines and the data lines being crossed with each other; each of the pixel units includes: a first thin-film transistor, a capacitor; the capacitor is connected to one of the data lines through the first thin-film transistor; each of the pixel units further includes: a connecting switch being controlled by the corresponding gate line; the connecting switch controls the connection or disconnection of the drain of the first thin-film transistor of an adjacent pixel unit which is at the same column and at a preceding row in relation to the pixel unit where the connecting switch belongs and the drain of the first thin-film transistor of another adjacent pixel unit which is at the same column and at a following row in relation to the pixel unit where the connecting switch belongs.

8. The pixel circuit as claimed in claim 7, wherein the connecting switch is a second thin-film transistor; a gate of the second thin-film transistor is connected to a gate line in the pixel unit where the second thin-film transistor belongs, a source thereof is connected to a drain of a first thin-film transistor of an adjacent pixel unit which is at the same column and at a preceding row, and a drain of the second thin-film transistor is connected to a drain of a first thin-film transistor of another adjacent pixel unit which is at the same column and at a following row.

9. The pixel circuit as claimed in claim 8, wherein when an input to the gate line is at a high electric potential, the second thin-film transistor is turned on, the drain of the first thin-film transistor of the adjacent pixel unit which is at the same column and at a preceding row and the drain of the first thin-film transistor of the another adjacent pixel unit which is at the same column and at a following row are connected to each other.

10. The pixel circuit as claimed in claim 7, wherein the capacitor includes a parasitic capacitor, a liquid crystal capacitor and a storage capacitor.

11. The pixel circuit as claimed in claim 8, wherein the capacitor includes a parasitic capacitor, a liquid crystal capacitor and a storage capacitor.

12. The pixel circuit as claimed in claim 9, wherein the capacitor includes a parasitic capacitor, a liquid crystal capacitor and a storage capacitor.

* * * * *

专利名称(译)	LCD阵列基板，LCD面板和LCD像素电路		
公开(公告)号	US20180231852A1	公开(公告)日	2018-08-16
申请号	US15/524661	申请日	2017-03-17
[标]申请(专利权)人(译)	深圳市华星光电技术有限公司		
申请(专利权)人(译)	深圳市中国星光电科技有限公司.		
当前申请(专利权)人(译)	深圳市中国星光电科技有限公司.		
[标]发明人	AN LIYANG		
发明人	AN, LIYANG		
IPC分类号	G02F1/1362 G02F1/1368 G02F1/1335		
CPC分类号	G02F1/136286 G02F1/1368 G02F2001/133397 G02F2201/123 G02F2001/136295 G02F1/133514 G02F1/13624		
优先权	201710082276.2 2017-02-15 CN		
其他公开文献	US10048557		
外部链接	USPTO		

摘要(译)

公开了一种LCD阵列基板，LCD面板和LCD像素电路。LCD阵列基板包括：基板和多条栅极线和数据线，其中栅极线和数据线彼此交叉以形成多个像素单元；每个像素单元设置有像素电极，第一薄膜晶体管和由相应栅极线控制的连接开关；控制开关控制开启。

